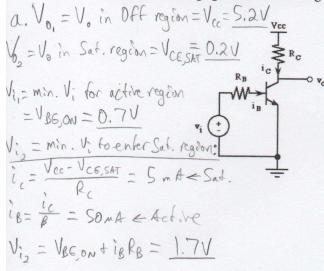
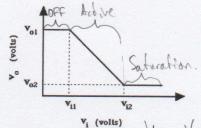
HKN ECE 110 Exam 3 Review Worksheet

- 1. For the following circuit, $V_{CC} = 5.2V$, $V_{BE,ON} = 0.7V$, $V_{CE,SAT} = 0.2V$ $R_B = 20k\Omega$, $R_C = 1k\Omega$ and $\beta = 100$.
 - a. Determine the values of Vol, Vo2, Vil, and Vi2.
 - b. What is the maximum value of A that keeps the BJT in the active region when:
 - i. $V_i = 1.2 + Asin(\omega t)$
 - ii. $V_i = 0.9 + Asin(\omega t)$
 - iii. $V_i = 1.4 + A\sin(\omega t)$
 - c. What is the voltage gain in the active region?

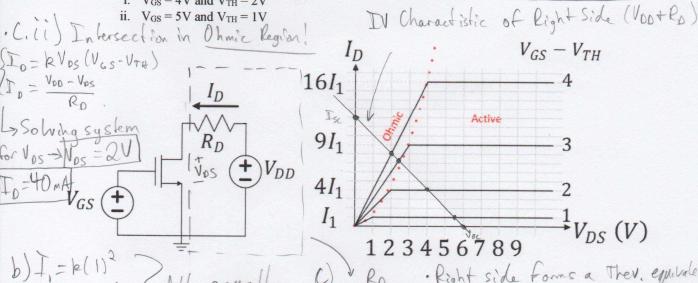


b. i) Amax = 0.5V Want to awid entering either ii) Amax = 0.2V off or saturation! Iii) Amax = 0.3V Must look at both input bounds, 0.7V and



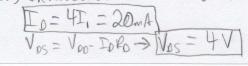
- 2. For the following circuit, $V_{DD} = 6V$, $R_D = 100\Omega$ and $I_1 = 5mA$.
 - a. List the equations for ID in the Ohmic and Active regions.
 - b. Using the equations from part (a), determine the value of k.
 - c. Find the values of ID and VDs when:
 - i. $V_{GS} = 4V$ and $V_{TH} = 2V$
 - ii. $V_{GS} = 5V$ and $V_{TH} = 1V$

a) Ohmic: In= kVos (VGS-VTH) Active: In = k(Vos-UTH)2



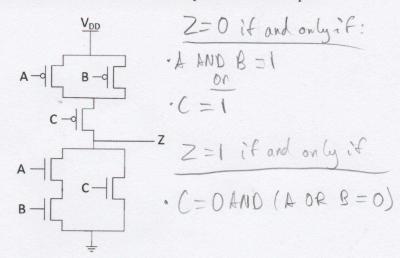
All equally 16I,= p(4) k=I, -> k= Smt/V2

· Right side forms a ther. equivalent. $-V_{oc} = V_{od} = 6V$ $-I_{sc} = \frac{V_{od}}{R_o} = 60 \text{ mA}$ · (Ci) Intersection in Active region!



3. Fill in the truth table for the following cMOS circuit where A, B and C are inputs and Z is the output.

A	BI	CMZ
0	0	0/1
0	0	11/10
0		10/11
0		11/0
	0	0/1
	0	1/10
1	1	0 0
	1	11/10



- 4. Suppose we have a square wave signal with $V_{rms} = 8V$ and $P_{avg} = 16W$ attached to some unknown load R. There is also some amount of sinusoidal noise corrupting the system.
 - a. What is the value of R?
 - b. Suppose the SNR of the system is 64. What is the amplitude of the noise signal?
 - c. What would be the new SNR of the system if the amplitude of the noise signal was doub

c. What would be the new SNR of the system if the amplitude of the noise signal was doubled?

A.
$$l_{avg} = \frac{V_{lms}}{R}$$

b) $SNR = \frac{l_{signal}}{l_{rosise}}$

$$= \frac{V_{lms}s_{sig}}{l_{signal}}$$

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C) A doubles $= V_{lms}s_{losise}$

Cuadruples

- 5. Lightning Round! The parts of this question are not related to one another
 - a. An IC has an operating frequency of 2.4 GHz, supply voltage of $V_{DD} = 5V$, and dissipates 10W. $\searrow \frac{1}{\sqrt{2}}$ the SNR
 - i. What is the new power dissipation if the supply voltage is increased to 15V?
 - ii. Suppose we want the IC to dissipate 15W by changing only the operating frequency. What should this

- sampled signal x[n].
 - i. List the frequencies present in the above signal (in Hertz).
 - ii. Find the values of x[n] at samples n = 0, 1, 2, 3, 4.
 - iii. What is the sampling frequency of this sampler?

i.
$$\cos(\omega t) = \cos(2\pi f t)$$
 ii. $\times \cos(2\pi f t)$ ii. $\times \cos(2\pi f t)$ iii. $\times \cos$

$$f_s = \frac{1}{T_s}$$

$$f_s = 8 + 2$$